



## 2SB1267/2SD1903

### 30V/8A High-Current Switching Applications

#### Applications

- Suitable for relay drivers, high-speed inverters, converters and other general high-current switching.

#### Features

- Suitable for sets whose height is restricted.
- Low collector to emitter saturation voltage :  $V_{CE(sat)} = -0.5V$  (PNP),  $0.4V$  (NPN) max.
- Large current capacity.

( ) : 2SB1267

#### Specifications

##### Absolute Maximum Ratings at $T_a = 25^\circ C$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	$V_{CB0}$		(-) $60$	V
Collector-to-Emitter Voltage	$V_{CEO}$		(-) $30$	V
Emitter-to-Base Voltage	$V_{EBO}$		(-) $6$	V
Collector Current	$I_C$		(-) $8$	A
Collector Current (Pulse)	$I_{CP}$		(-) $15$	A
Collector Dissipation	$P_C$		$1.65$	W
		$T_c = 25^\circ C$	$30$	W
Junction Temperature	$T_J$		$150$	$^\circ C$
Storage Temperature	$T_{stg}$		$-55$ to $+150$	$^\circ C$

##### Electrical Characteristics at $T_a = 25^\circ C$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	$I_{CB0}$	$V_{CB} = (-)40V, I_E = 0$			(-) $0.1$	$\mu A$
Emitter Cutoff Current	$I_{EBO}$	$V_{EB} = (-)4V, I_C = 0$			(-) $0.1$	$\mu A$
DC Current Gain	$h_{FE1}$	$V_{CE} = (-)2V, I_C = (-)1A$	$70^*$		$280^*$	
	$h_{FE2}$	$V_{CE} = (-)2V, I_C = (-)4A$	$30$			
Gain-Bandwidth Product	$f_T$	$V_{CE} = (-)5V, I_C = (-)1A$		$120$		MHz
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = (-)3A, I_B = (-)0.15A$			$0.4$	V
					(-) $0.5$	V

\* : The 2SB1267/2SD1903 are classified by  $1A h_{FE}$  as follows :

70	Q	140	100	R	200	140	S	280
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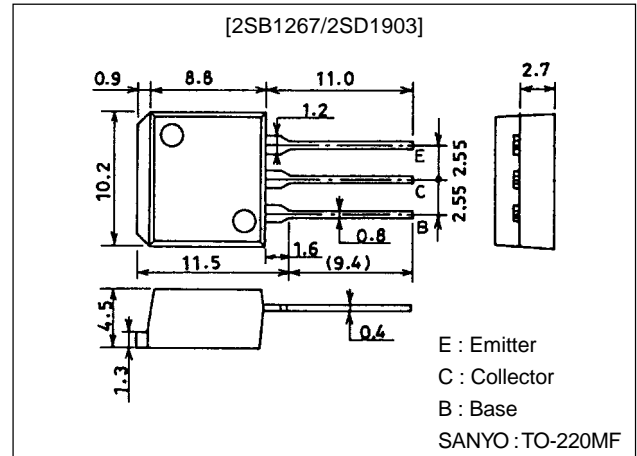
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#### Package Dimensions

unit:mm

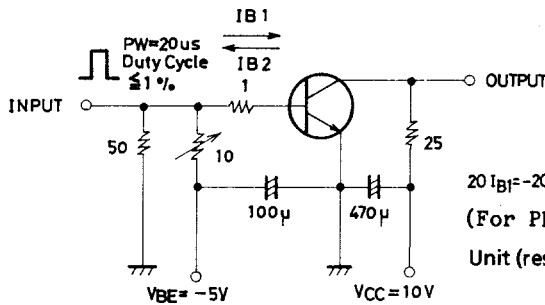
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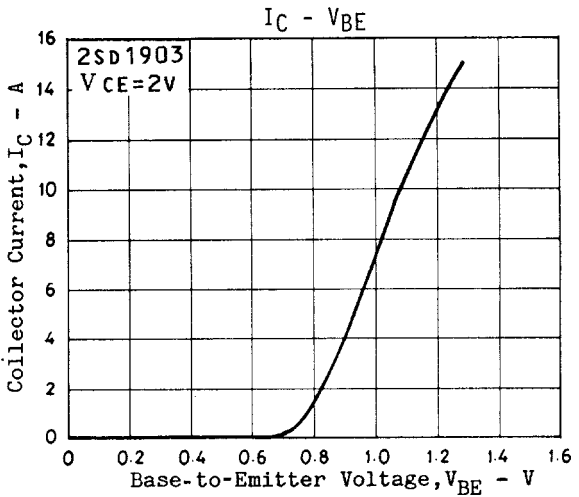
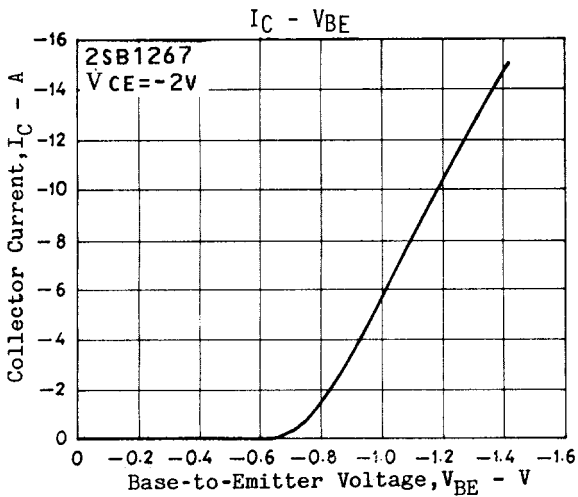
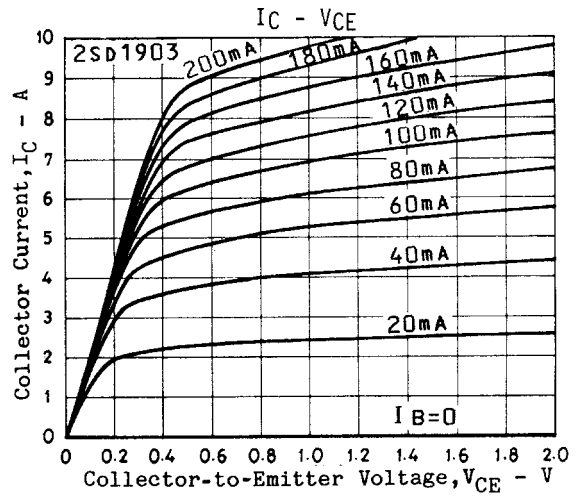
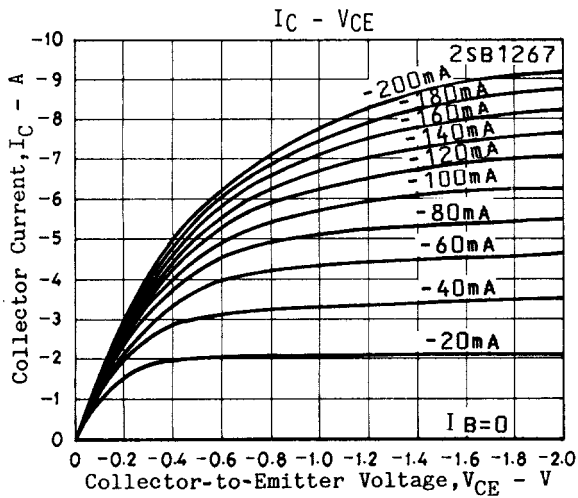
# 2SB1267/2SD1903

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = (-)1mA, I_E = 0$	(-)60			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = (-)1mA, R_{BE} = \infty$	(-)30			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = (-)1mA, I_C = 0$	(-)6			V
Turn-ON Time	$t_{on}$	See specified test circuit.		0.1		$\mu s$
Storage Time	$t_{stg}$	See specified test circuit.		(0.2)		$\mu s$
				0.5		$\mu s$
Fall Time	$t_f$	See specified test circuit.		0.03		$\mu s$

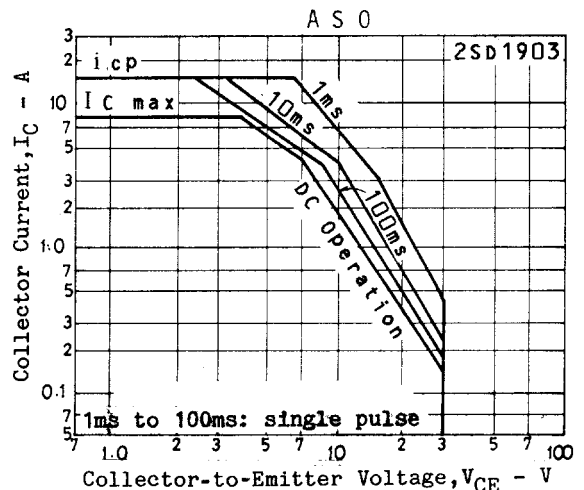
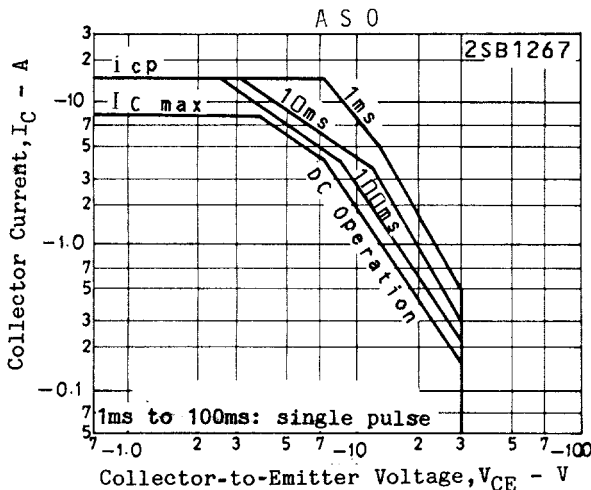
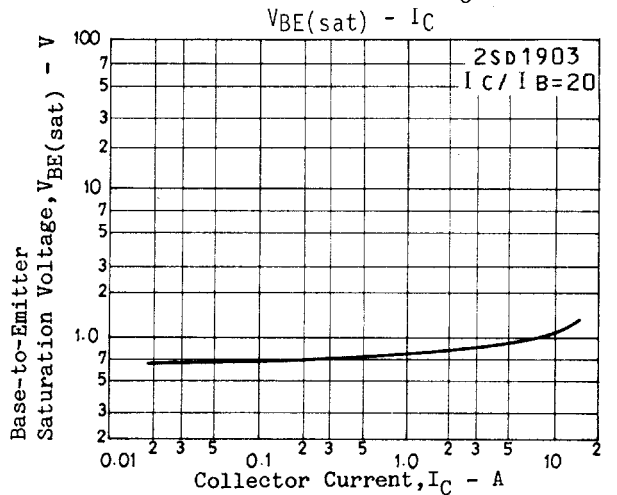
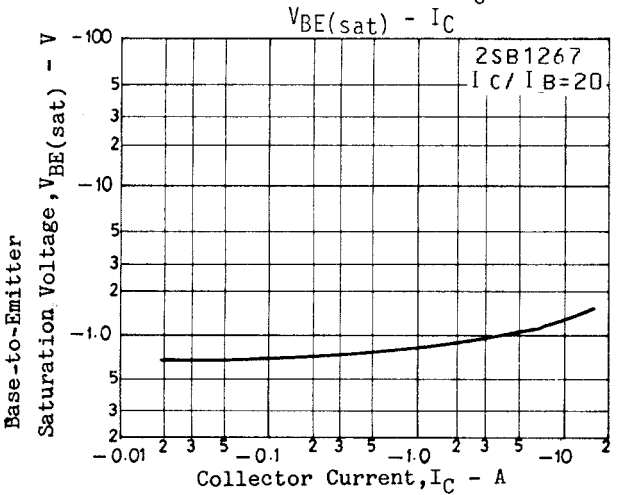
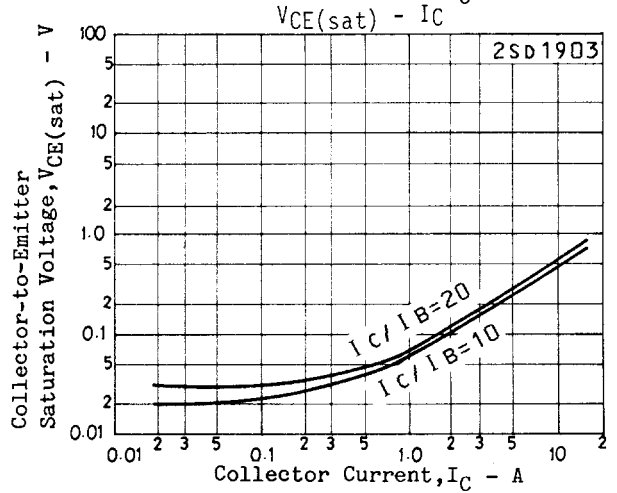
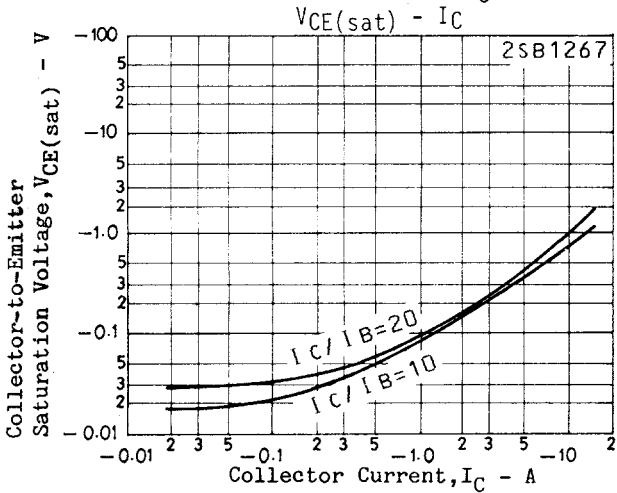
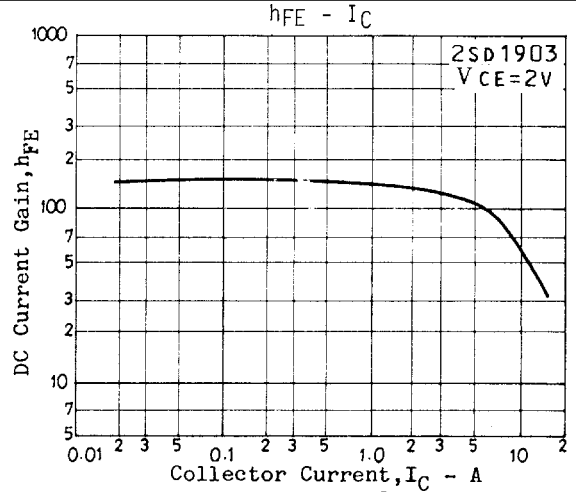
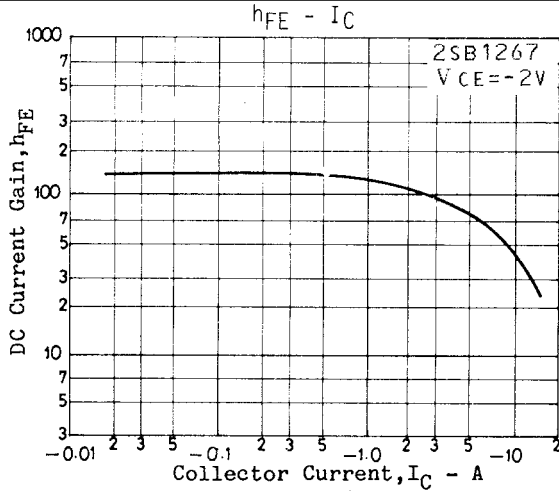
## Switching Time Test Circuit



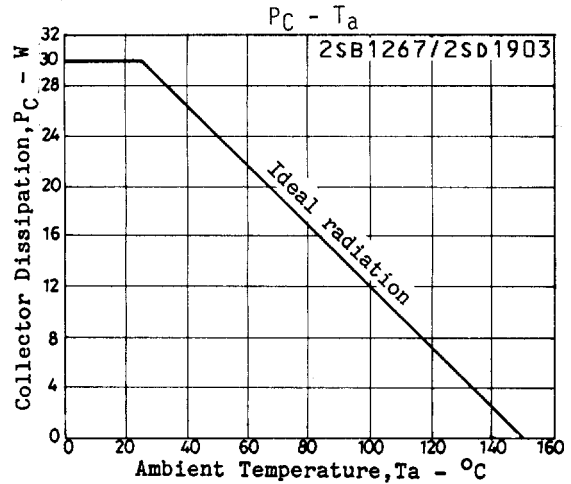
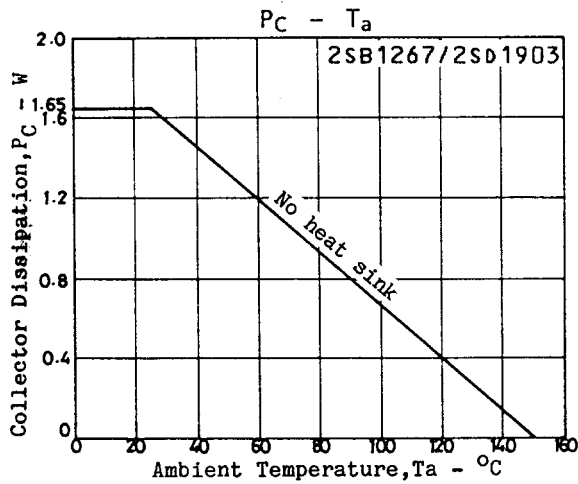
$20 I_{B1} = -20 I_{B2} = I_C = 4A$   
 (For PNP, the polarity is reversed.)  
 Unit (resistance:  $\Omega$ , capacitance: F)



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